



2N7002KTB

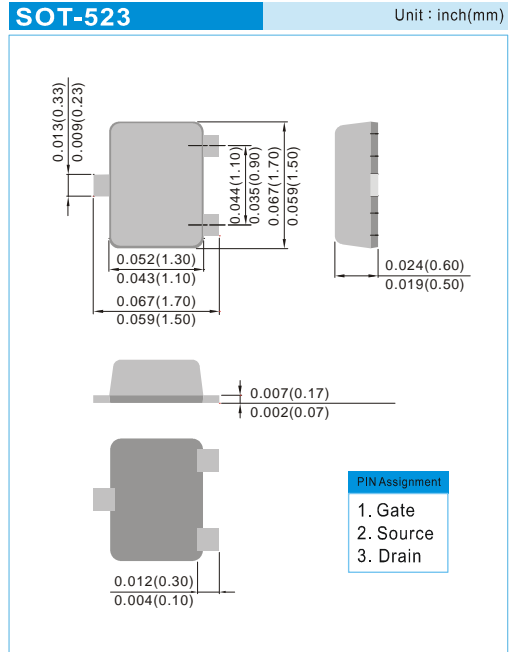
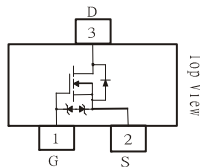
60V N-Channel Enhancement Mode MOSFET - ESD Protected

FEATURES

- $R_{DS(ON)}$, V_{GS} @ $10V$, I_{DS} @ $500mA=3\Omega$
- $R_{DS(ON)}$, V_{GS} @ $4.5V$, I_{DS} @ $200mA=4\Omega$
- Advanced Trench Process Technology
- High Density Cell Design For Ultra Low On-Resistance
- Very Low Leakage Current In Off Condition
- Specially Designed for Battery Operated Systems, Solid-State Relays Drivers : Relays, Displays, Lamps, Solenoids, Memories, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std. . (Halogen Free)

MECHANICAL DATA

- Case: SOT-523 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.00007 ounces, 0.002 grams
- Marking: 27



Maximum RATINGS and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER	Symbol	Limit	Units
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	115	mA
Pulsed Drain Current ¹⁾	I_{DM}	800	mA
Maximum Power Dissipation	P_D	$T_A=25^\circ C$	200
		$T_A=75^\circ C$	150
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to + 150	$^\circ C$
Junction-to Ambient Thermal Resistance(PCB mounted) ²⁾	$R_{\theta JA}$	883	$^\circ C/W$

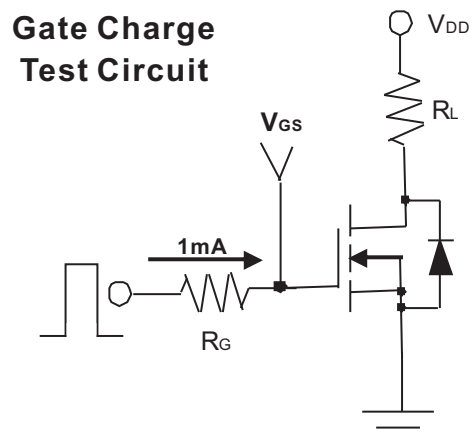
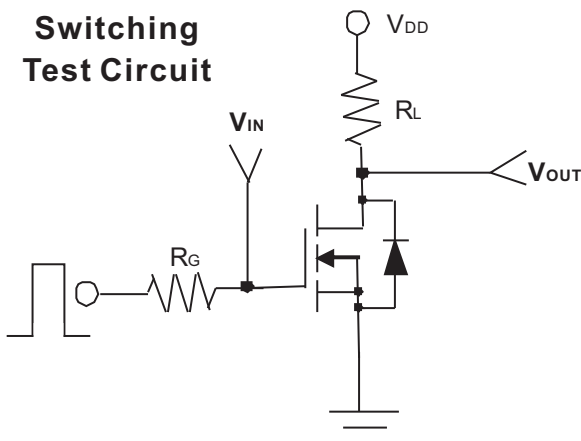
- Note:1.Maximum DC current limited by the package
 2.Surface mounted on FR4 board, $t \leq 10$ sec
 3.Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$



2N7002KTB

ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Units
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=10\mu A$	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1	-	2.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=200mA$	-	-	4.0	Ω
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=500mA$	-	-	3.0	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V$	-	-	1	μA
Gate Body Leakage	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 10	μA
Forward Transconductance	g_{fs}	$V_{DS}=15V, I_D=250mA$	100	-	-	mS
Dynamic						
Total Gate Charge	Q_g	$V_{DS}=15V, I_D=200mA$ $V_{GS}=4.5V$	-	-	0.8	nC
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=30V, R_L=150\Omega$ $I_D=200mA, V_{GEN}=10V$ $R_G=10\Omega$	-	-	20	ns
Turn-Off Delay Time	$t_{d(off)}$		-	-	125	
Input Capacitance	C_{iss}	$V_{DS}=25V, V_{GS}=0V$ $f=1.0MHz$	-	-	35	μF
Output Capacitance	C_{oss}		-	-	10	
Reverse Transfer Capacitance	C_{rss}		-	-	5	
Source-Drain Diode						
Diode Forward Voltage	V_{SD}	$I_S=200mA, V_{GS}=0V$	-	0.82	1.3	V
Continuous Diode Forward Current	I_S	-	-	-	115	mA
Pulsed Diode Forward Current	I_{SM}	-	-	-	800	mA





2N7002KTB

Typical Characteristics Curves ($T_A=25^\circ\text{C}$, unless otherwise noted)

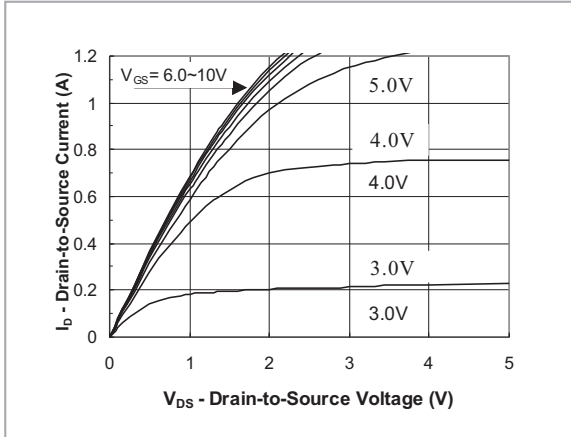


FIG.1- Output Characteristic

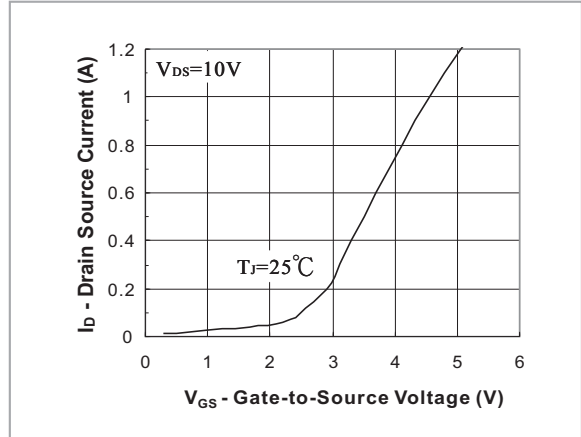


FIG.2- Transfer Characteristic

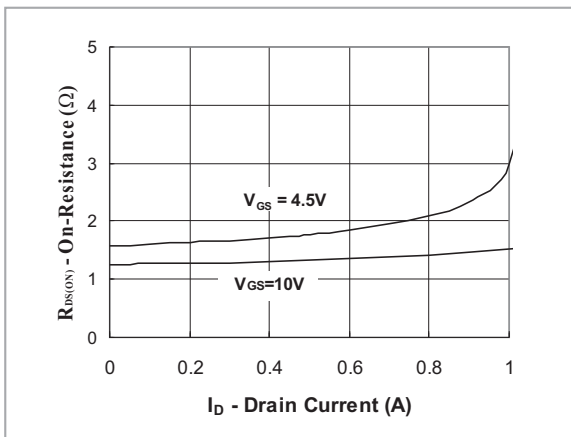


FIG.3- On Resistance vs Drain Current

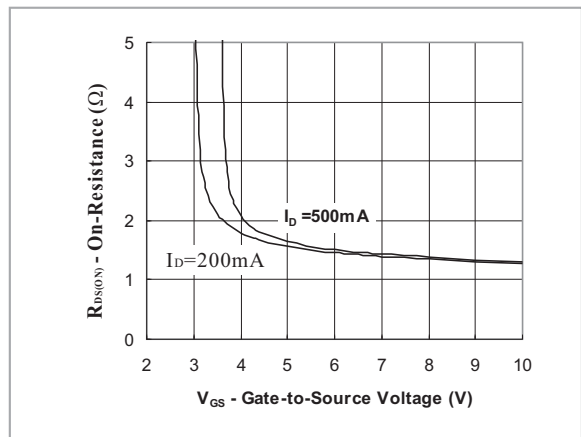


FIG.4- On Resistance vs Gate to Source Voltage

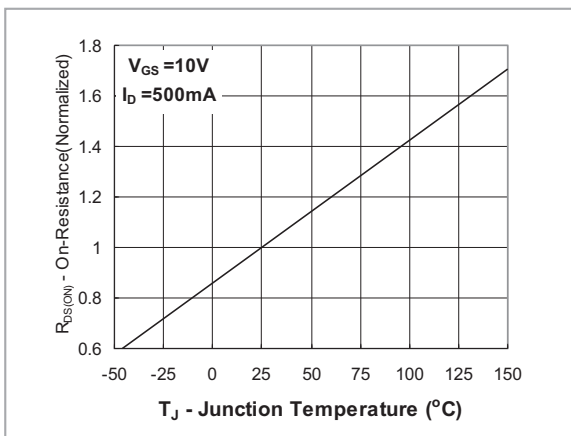


FIG.5- On Resistance vs Junction Temperature



2N7002KTB

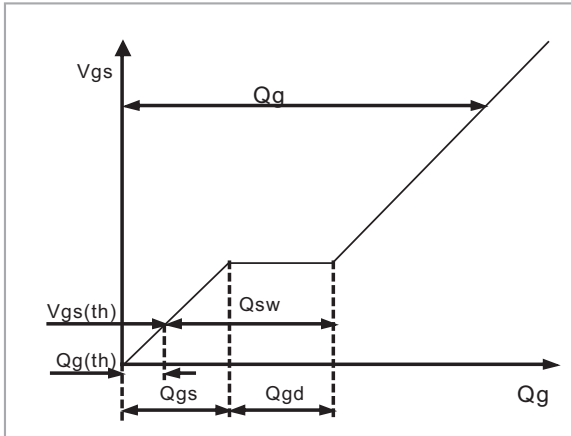


Fig.6 - Gate Charge Waveform

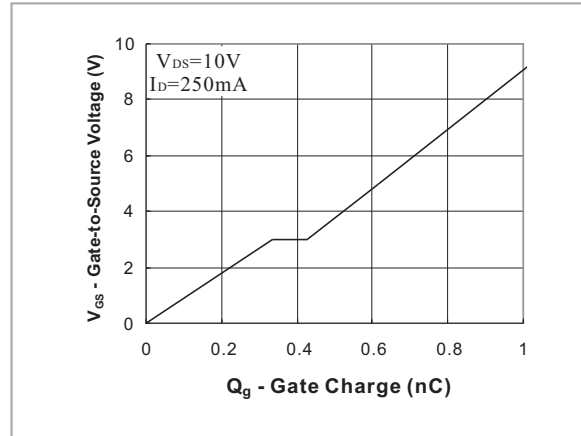


Fig.7 - Gate Charge

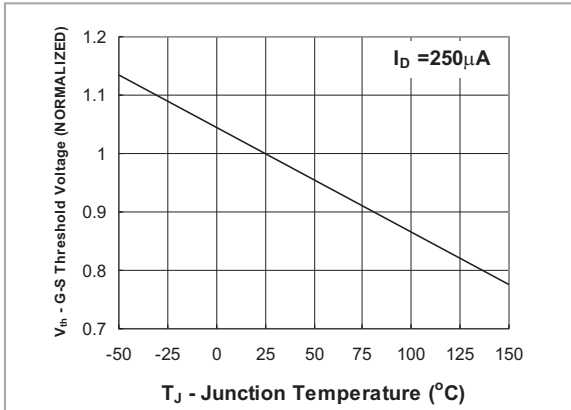


Fig.8 - Threshold Voltage vs Temperature

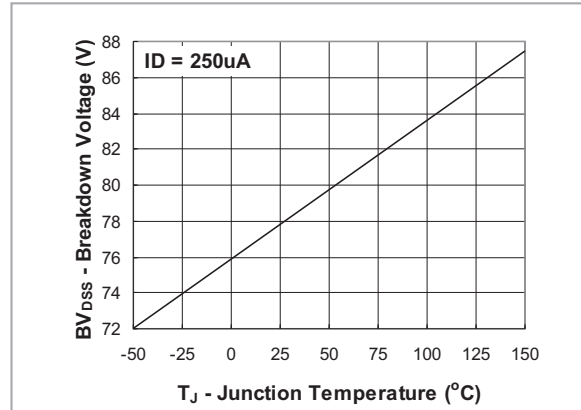


Fig.9 - Breakdown Voltage vs Junction Temperature

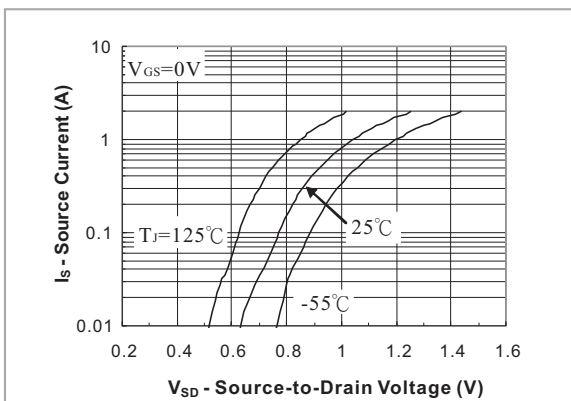


Fig.10 - Source-Drain Diode Forward Voltage

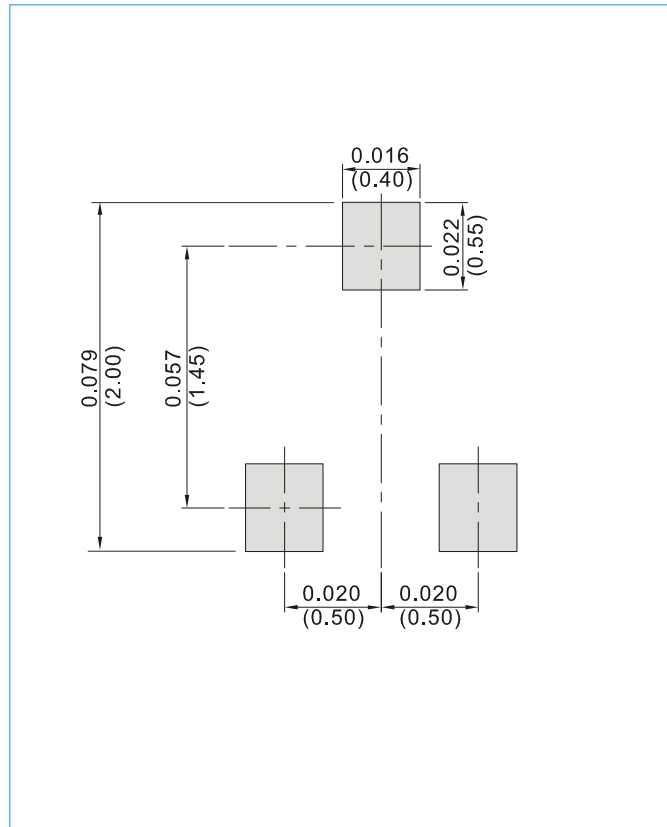


2N7002KTB

MOUNTING PAD LAYOUT

SOT-523

Unit : inch(mm)



ORDER INFORMATION

- Packing information
T/R - 4K per 7" plastic Reel



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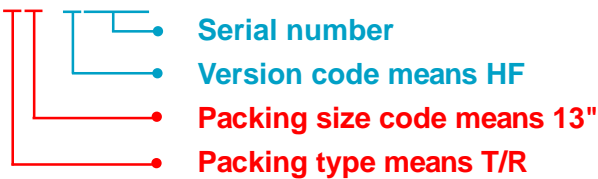
Part No_packing code_Version

2N7002KTB_R1_00001

For example :

RB500V-40_R2_00001

Part No.



Packing Code XX				Version Code XXXXX		
Packing type	1 st Code	Packing size code	2 nd Code	HF or RoHS	1 st Code	2 nd ~5 th Code
Tape and Ammunition Box (T/B)	A	N/A	0	HF	0	serial number
Tape and Reel (T/R)	R	7"	1	RoHS	1	serial number
Bulk Packing (B/P)	B	13"	2			
Tube Packing (T/P)	T	26mm	X			
Tape and Reel (Right Oriented) (TRR)	S	52mm	Y			
Tape and Reel (Left Oriented) (TRL)	L	PANASERT T/B CATHODE UP (PBCU)	U			
FORMING	F	PANASERT T/B CATHODE DOWN (PBCD)	D			



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